

1N5555, 1N5556, 1N5557, 1N5635A thru 1N5661A

1500W Transient Voltage Suppressor Diodes

TECHNICAL DATA DATA SHEET 5501, REV. A

AVAILABLE AS 1N, JAN, JANTXV

1500W Unipolar TVS Diode in DO-13 Package

Qualified per MIL-PRF-19500/500

DESCRIPTION:

This DO-13 hermetically sealed unipolar TVS diode series is military qualified per MIL-PRF-19500/500 and is targeted for space, commercial and military aircraft, military vehicles, shipboard markets and all high reliability applications.

FEATURES / BENEFITS:

- ✓ Hermetic sealed DO-13 package
- ✓ Parts are hot solder dipped
- ✓ JAN/ JANTX/ JANTXV available per MIL-PRF-19500/500

MAXIMUM RATINGS

- ✓ Operating & Storage Temperature: -65°C to +175°C
- ✓ Junction Temperature: -65°C to +175°C

ELECTRICAL CHARACTERISTICS

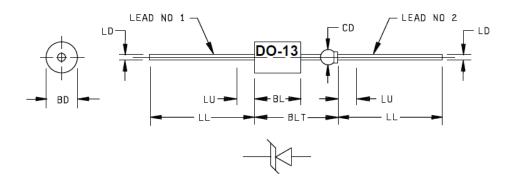
SERIES TYPE	MIN BREAKDOWN VOLTAGE ^V (BR) @ ^I (BR)		WORKING PEAK REVERSE VOLTAGE VRWM	MAXIMUM STANDBY CURRENT ID	MAX. CLAMP. VOLTAGE VC @ Ipp tp = 1ms	MAX. PEAK PULSE CURRENT tp = 1ms, tr = 10μs I _{PP}	MAX. TEMP. COEFFICIENT V(BR)
1500W	Vdc	mA dc	Vdc	μAdc	V(pk)	A(pk)	% / °C
1N5635A	11.40	1	10.20	5	16.7	90.0	.078
1N5636A	12.40	1	11.10	5	18.2	82.0	.081
1N5637A	14.30	1	12.80	5	21.2	71.0	.084
1N5638A	15.20	1	13.60	5	22.5	67.0	.086
1N5639A	17.10	1	15.30	5	25.2	59.5	.088
1N5640A	19.00	1	17.10	5	27.7	54.0	.090
1N5641A	20.90	1	18.80	5	30.6	49.0	.092
1N5642A	22.80	1	20.50	5	33.2	45.0	.094
1N5643A	25.70	1	23.10	5	37.5	40.0	.096
1N5644A	28.50	1	25.60	5	41.4	36.0	.097
1N5645A	31.40	1	28.20	5	45.7	33.0	.098
1N5555	33.00	1	30.50	5	47.5	32.0	.093
1N5646A	34.20	1	30.80	5	49.9	30.0	.099
1N5647A	37.10	1	33.30	5	53.9	28.0	.100
1N5648A	40.90	1	36.80	5	59.3	25.3	.101
1N5556	43.70	1	40.30	5	63.5	24.0	.094
1N5649A	44.70	1	40.20	5	64.8	23.2	.101
1N5650A	48.50	1	43.60	5	70.1	21.4	.102
1N5651A	53.20	1	47.80	5	77.0	19.5	.103

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1500W	Vdc	mA dc	Vdc	μAdc	V(pk)	A(pk)	% / °C
1N5557	54.00	1	49.00	5	78.5	19.0	.096
1N5652A	58.90	1	53.00	5	85.0	17.7	.104
1N5653A	64.60	1	58.10	5	92.0	16.3	.104
1N5654A	71.30	1	64.10	5	103.0	14.6	.105
1N5655A	77.90	1	70.10	5	113.0	13.3	.105
1N5656A	86.50	1	77.80	5	125.0	12.0	.106
1N5657A	95.00	1	85.50	5	137.0	11.0	.106
1N5658A	105.00	1	94.00	5	152.0	9.9	.107
1N5659A	114.00	1	102.00	5	165.0	9.1	.107
1N5660A	124.00	1	111.00	5	179.0	8.4	.107
1N5661A	143.00	1	128.00	5	207.0	7.2	.108

PACKAGE DIMENSIONS (inches/mm)



Symbol	Inc	hes	Millimeters		Notes
_	Min	Max	Min	Max	
BD	.215	.235	5.46	5.97	
BL	.293	.357	7.44	9.07	3
BLT		.570		14.48	
CD	.045	.100	1.14	2.54	5
LD	.025	.035	0.64	0.89	
LL	1.000	1.625	25.40	41.28	4
LU		.188		4.78	4

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. The major diameter is essentially constant along its length.
- 4. Within this zone, diameter may vary to allow for lead finishes and irregularities.
- 5. Dimension to allow for pinch or seal deformation anywhere along tubulation.
 6. Lead 1 (cathode) shall be electrically connected to the case.
- 7. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

PKG: DO-13



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PART ORDERING INFORMATION

The following part numbers can be screened and tested to the military screening flow. The parts are marked in accordance with the testing performed, example:

Sensitron Screening Level	*Part Number Leaded Package (example for 1N5555)		
1N	1N5555		
JAN	JAN1N5555		
JANTX	JANTX1N5555		
JANTXV	JANTXV1N5555		

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